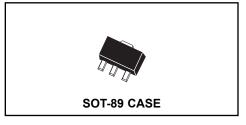
CXSH-4

SURFACE MOUNT SILICON SCHOTTKY BARRIER RECTIFIER



MAXIMUM RATINGS (TA=25°C)

Central™ Semiconductor Corp.

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CXSH-4 type is a Schottky barrier rectifier mounted in an epoxy molded case using a metal to silicon junction to yield low forward voltage drop. This device utilizes a single chip with anode connections made to PIN 1 and PIN 3.

MARKING CODE: FULL PART NUMBER

	SYMBOL		UNITS	
Peak Repetitive Reverse Voltage	V_{RRM}	40	V	
DC Blocking Voltage	V_{R}	40	V	
RMS Reverse Voltage	V _{R(RMS)}	28	V	
Average Forward Current	IO	1.0	Α	
Peak Forward Surge Current (8.3ms, Non-Rep.)	IFSM	10	Α	
Operating and Storage				
Junction Temperature	T_{J} , T_{stq}	-65 to +150	°C	

$\textbf{ELECTRICAL CHARACTERISTICS} \quad (T_{\mbox{\scriptsize M}} = 25^{\circ}\mbox{C unless otherwise noted})$

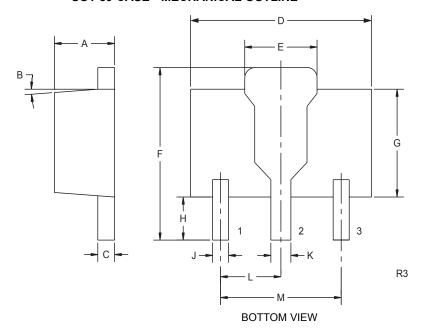
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{R}	V _R =40V		1.0	mA
I_{R}	V _R =40V, T _A =100°C		10	mA
V_{F}	I _F =1.0A		0.55	V



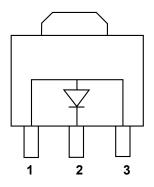
CXSH-4

SURFACE MOUNT SILICON SCHOTTKY BARRIER RECTIFIER

SOT-89 CASE - MECHANICAL OUTLINE



MARKING CODE: FULL PART NUMBER



INC MIN	HES MAX	MILLIM	ETEDO	
MIN	NAA V		MILLIMETERS	
	IVIAX	MIN	MAX	
0.055	0.067	1.40	1.70	
4°		4°		
0.016	0.018	0.40	0.46	
0.173	0.185	4.40	4.70	
0.070	0.074	1.79	1.87	
0.146	0.177	3.70	4.50	
0.094	0.106	2.40	2.70	
0.028	0.051	0.70	1.30	
0.015	0.019	0.38	0.48	
0.019	0.023	0.48	0.58	
0.059		1.50		
0.118		3.00		
	4 0.016 0.173 0.070 0.146 0.094 0.028 0.015 0.019	4° 0.016 0.018 0.173 0.185 0.070 0.074 0.146 0.177 0.094 0.106 0.028 0.051 0.015 0.019 0.019 0.023 0.059 0.118	4° 40.016 0.018 0.40 0.173 0.185 4.40 0.070 0.074 1.79 0.146 0.177 3.70 0.094 0.106 2.40 0.028 0.051 0.70 0.015 0.019 0.38 0.019 0.023 0.48 0.059 1.	

SOT-89 (REV: R3)

LEAD CODE:

- 1) ANODE
- 2) CATHODE
- 3) ANODE

PIN 2 IS COMMON TO THE TAB

R4 (18-November 2002)